



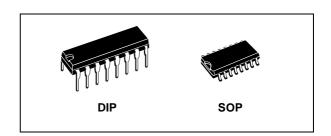
## HEX BUFFER/CONVERTER (INVERTING)

- PROPAGATION DELAY TIME: t<sub>PD</sub> = 40ns (TYP.) at V<sub>DD</sub> = 10V C<sub>L</sub> = 50pF
- HIGH TO LOW LEVEL LOGIC CONVERSION
- HIGH "SINK" AND "SOURCE" CURRENT CAPABILITY
- QUIESCENT CURRENT SPECIFIED UP TO 20V
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT I<sub>I</sub> = 100nA (MAX) AT V<sub>DD</sub> = 18V T<sub>A</sub> = 25°C
- 100% TESTED FOR QUIESCENT CURRENT



The HCF4049UB is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages. It is an inverting Hex Buffer/Converter and feature logic level conversions using only one supply voltage ( $V_{DD}$ ).

The input high level signal ( $V_{IH}$ ) can exceed the  $V_{DD}$  supply voltage when these devices are used

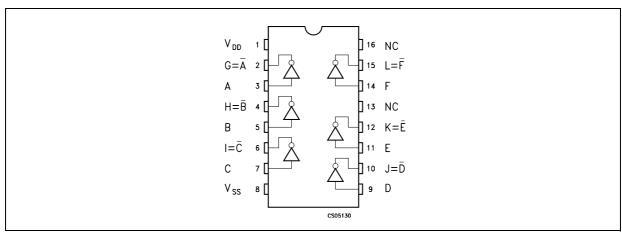


#### **ORDER CODES**

PACKAGE	TUBE	T&R
DIP	HCF4049UBEY	
SOP	HCF4049UBM1	HCF4049UM013TR

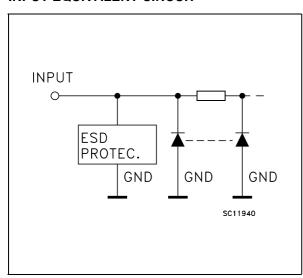
for logic level conversions. This device is intended for use as CMOS to DTL/TTL converters and can drive directly two DTL/TTL loads ( $V_{DD}$  = 5V,  $V_{OL} \le 0.4V$  and  $I_{OL} \le 3.2$ mA.

#### **PIN CONNECTION**



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### **INPUT EQUIVALENT CIRCUIT**



### **PIN DESCRIPTION**

PIN N°	SYMBOL	NAME AND FUNCTION
3, 5, 7, 9, 11, 14	A, B, C, D, E, F	Data Inputs
2, 4, 6, 10, 12, 15	G, H, I, J, K, L	Data Outputs
13, 16	NC	Not Connected
8	$V_{SS}$	Negative Supply Voltage
1	$V_{DD}$	Positive Supply Voltage

### **TRUTH TABLE**

INPUTS	OUTPUTS
A, B, C, D,E, F	G, H, I, J, K, L
L	Н
Н	L

## **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
$V_{DD}$	Supply Voltage	-0.5 to +22	V
V <sub>I</sub>	DC Input Voltage	-0.5 to +18	V
I <sub>I</sub>	DC Input Current	± 10	mA
P <sub>D</sub>	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T <sub>op</sub>	Operating Temperature	-55 to +125	°C
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V<sub>SS</sub> pin voltage.

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**RECOMMENDED OPERATING CONDITIONS** 

Symbol	Parameter	Value	Unit
$V_{DD}$	Supply Voltage	3 to 20	V
V <sub>I</sub>	Input Voltage	-0.5 to 15V	V
T <sub>op</sub>	Operating Temperature	-55 to 125	°C

## **DC SPECIFICATIONS**

			Test Con	dition		Value							
Symbol	Parameter	VI	v <sub>o</sub>	ΙΙοΙ	V <sub>DD</sub>	T <sub>A</sub> = 25°C			-40 to 85°C		-55 to 125°C		Unit
		(V)	(V)	(μ <b>A</b> )	(V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
ΙL	Quiescent Current	0/5			5		0.02	1		30		30	
		0/10			10		0.02	2		60		60	μΑ
		0/15			15		0.02	4		120		120	μΛ
		0/20			20		0.04	20		600		600	
$V_{OH}$	High Level Output	0/5		<1	5	4.95			4.95		4.95		
	Voltage	0/10		<1	10	9.95			9.95		9.95		V
		0/15		<1	15	14.95			14.95		14.95		
$V_{OL}$	Low Level Output	5/0		<1	5		0.05			0.05		0.05	
	Voltage	10/0		<1	10		0.05			0.05		0.05	V
		15/0		<1	15		0.05			0.05		0.05	
$V_{IH}$	High Level Input		0.5/4.5	<1	5	4			4		4		
	Voltage		1/9	<1	10	8			8		8		V
			1.5/13.5	<1	15	12			12		12		
$V_{IL}$	Low Level Input		4.5/0.5	<1	5			1		1		1	
	Voltage		9/1	<1	10			2		2		2	V
			13.5/1.5	<1	15			3		3		3	
$I_{OH}$	Output Drive	0/5	2.5	<1	5	-1.25	-6.4		-0.42		-0.42		
	Current	0/5	4.6	<1	5	-0.51	-1.6		-0.38		-0.38		mA
		0/10	9.5	<1	10	-1.25	-3.6		-1		-1		1117 (
		0/15	13.5	<1	15	-3.75	-12		-3		-3		
$I_{OL}$	Output Sink	0/5	0.4	<1	5	3.2	6.4		2.6		2.6		
Current	0/10	0.5	<1	10	8	16		6.6		6.6		mΑ	
		0/15	1.5	<1	15	24	48		19		19		
I <sub>I</sub>	Input Leakage Current	0/18	Any In	put	18		±10 <sup>-5</sup>	±0.1		±1		±1	μΑ
CI	Input Capacitance		Any In	put			5	7.5					pF

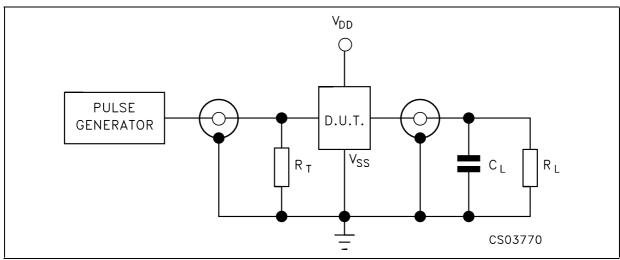
The Noise Margin for both "1" and "0" level is: 1V min. with  $V_{DD}$ =5V, 2V min. with  $V_{DD}$ =10V, 2.5V min. with  $V_{DD}$ =15V

# $\textbf{DYNAMIC ELECTRICAL CHARACTERISTICS} \; (T_{amb} = 25 ^{\circ}C, \; C_{L} = 50 \text{pF}, \; R_{L} = 200 \text{K}\Omega, \; t_{r} = t_{f} = 20 \; \text{ns})$

Symbol	_		Test Condition				Value (*)		
	Parameter	V <sub>DD</sub> (V)	V <sub>I</sub> (V)		Min.	Тур.	Max.		
t <sub>TLH</sub>	Output Transition Time	5	5			80	160		
		10	10			40	80	ns	
		15	15			30	60		
t <sub>THL</sub>	Output Transition Time	5	5			30	60		
		10	10			20	40	ns	
		15	15			15	30		
t <sub>PLH</sub>	Propagation Delay Time	5	5			60	120		
		10	10			32	65		
		5	10			45	90	ns	
		15	15			25	50		
		5	15			45	90		
t <sub>PHL</sub>	Propagation Delay Time	5	5			32	65		
	10	10			20	40			
		5	10			15	30	ns	
		15	15			15	30		
		5	15			10	20		

<sup>(\*)</sup> Typical temperature coefficient for all V<sub>DD</sub> value is 0.3%/°C.

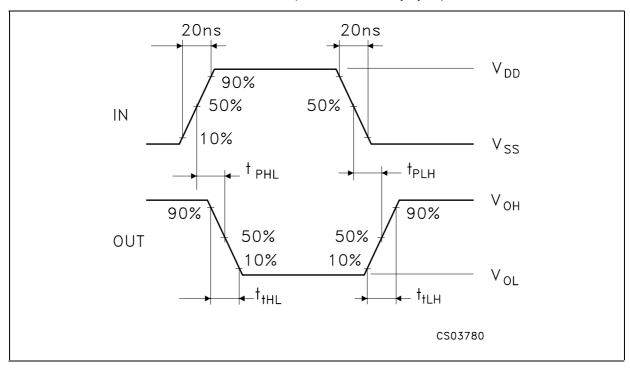
### **TEST CIRCUIT**



 $C_L$  = 50pF or equivalent (includes jig and probe capacitance)  $R_L$  = 200K $\Omega$   $R_T$  =  $Z_{OUT}$  of pulse generator (typically 50 $\Omega$ )

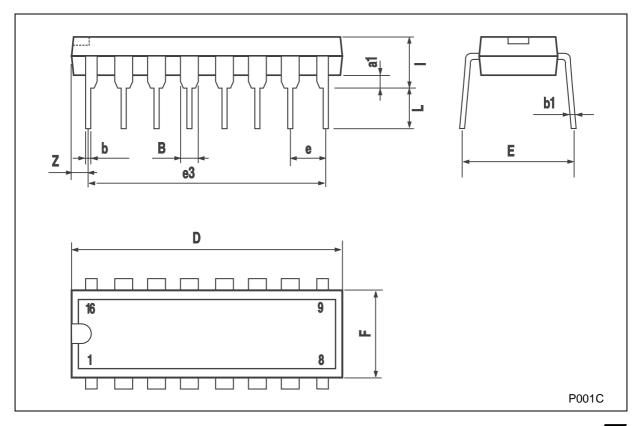
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## WAVEFORM: PROPAGATION DELAY TIMES (f=1MHz; 50% duty cycle)



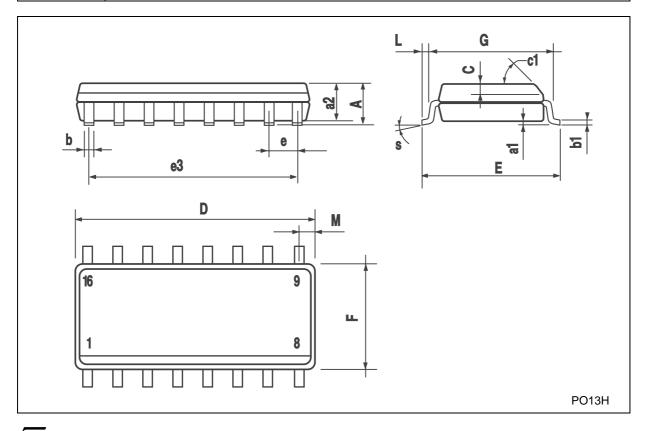
# Plastic DIP-16 (0.25) MECHANICAL DATA

DIM		mm.		inch		
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
В	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
е		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050

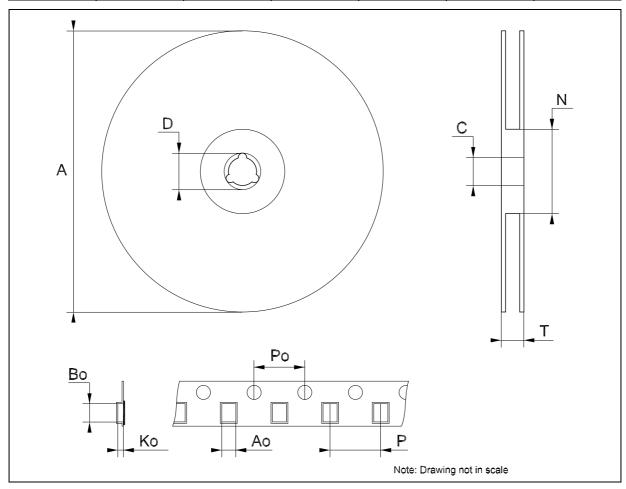


## **SO-16 MECHANICAL DATA**

DIM		mm.		inch				
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
Α			1.75			0.068		
a1	0.1		0.2	0.004		0.008		
a2			1.65			0.064		
b	0.35		0.46	0.013		0.018		
b1	0.19		0.25	0.007		0.010		
С		0.5			0.019			
c1			45°	(typ.)				
D	9.8		10	0.385		0.393		
Е	5.8		6.2	0.228		0.244		
е		1.27			0.050			
e3		8.89			0.350			
F	3.8		4.0	0.149		0.157		
G	4.6		5.3	0.181		0.208		
L	0.5		1.27	0.019		0.050		
M			0.62			0.024		
S	8		° (r	nax.)		•		



DIM		mm.		inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
N	60			2.362			
Т			22.4			0.882	
Ao	6.45		6.65	0.254		0.262	
Во	10.3		10.5	0.406		0.414	
Ko	2.1		2.3	0.082		0.090	
Po	3.9		4.1	0.153		0.161	
Р	7.9		8.1	0.311		0.319	



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